

# **DATASHEET**

#### ITR8307/TR8

#### **Features**

- Fast response time
- High sensitivity
- Cut-Off visible wavelength
- Thin
- Compact
- Pb free
- This product itself will remain within RoHS compliant version.
- Compliance with EU REACH
- Compliance Halogen Free(Br < 900ppm, Cl < 900ppm, Br+Cl < 1500ppm)



<u>ITR8307/TR8</u> is a light reflection switch which includes a GaAs IR-LED transmitter and a NPN photo-transistor with a high sensitive receiver for short distance, operating in the infrared range. Both components are mounted side- by- side in a plastic package.

#### **Applications**

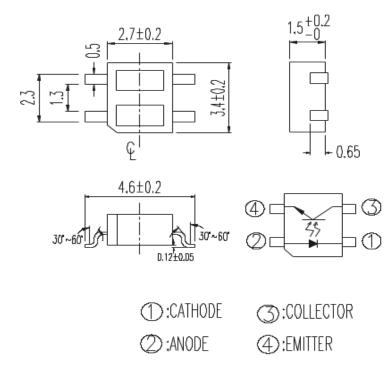
- Camera
- VCR
- Floppy disk driver
- Cassette type recorder
- Various microcomputer control equipment

#### **Device Selection Guide**

Device No.	Chip Material
IR	GaAs
PT	Silicon



## **Package Dimensions**



**Notes:** 1.All dimensions are in millimeters

2. Tolerances unless dimensions ±0.15mm

## **Absolute Maximum Ratings (Ta=25°C)**

	Parameter	Symbol	Rating	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
	Reverse Voltage	$V_R$	5	V
	Forward Current	$I_{\mathrm{F}}$	50	mA
	Peak Forward Current (*1)	$ m I_{FP}$	1	A
Output	Collector Power Dissipation	$P_{\rm C}$	75	mW
	Collector Current	$I_{C}$	50	mA
	Collector-Emitter Voltage	$B V_{CEO}$	30	V
	Emitter-Collector Voltage	$B V_{ECO}$	5	V
Operatin	g Temperature	Topr	-25~+85	$^{\circ}\!\mathbb{C}$
Storage Temperature		Tstg	-30~+90	$^{\circ}\!\mathbb{C}$
Lead Soldering Temperature (*2)		Tsol	260	$^{\circ}\!\mathbb{C}$

Notes: ( $\pm 1$ ) tw=100  $\mu$ sec., T=10 msec. ( $\pm 2$ ) t=5 Sec



# **Electro-Optical Characteristics (Ta=25°C)**

Pa	arameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input	Forward Voltage	$V_{\mathrm{F}}$		1.2	1.6	V	I <sub>F</sub> =20mA
	Reverse Current	$I_R$			10	μΑ	V <sub>R</sub> =5V
	Peak Wavelength	$\lambda_{ m P}$		940		nm	I <sub>F</sub> =20mA
Output	Dark Current	$I_{CEO}$			100	nA	V <sub>CE</sub> =10 V
	C-E Saturation Voltage	V <sub>CE(sat)</sub>			0.4	V	Ic=20mA Ee=1mW/cm <sup>2</sup>
Transfer Characteristics	Collector Current	I <sub>C(ON)</sub>	0.3		0.8	mA	V <sub>CE</sub> =5V I <sub>F</sub> =20mA
	Leakage Current	I <sub>LEAK</sub>			1	μΑ	
	Rise time	$t_{\rm r}$		20		μs	$V_{CE}=2V$ $I_{C}=100\mu A$ $R_{L}=1k\Omega$
	Fall time	$t_{\mathrm{f}}$		20		μs	

### Rank

 $Conditions : I_F\!\!=\!\!20mA \quad V_{CE}\!\!=\!\!5V$ 

Unit: µA

Bin number	Min	Max
В	300	600
С	500	800

### Typical Electrical/Optical/Characteristics Curves for IR

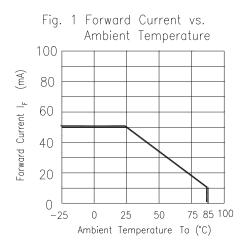


Fig. 3 Peak Emission Wavelength vs. Ambient Temperature

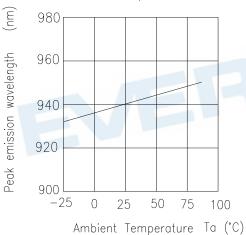


Fig. 5 Forward Voltage vs.

Ambient Temperature

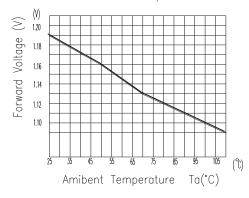


Fig. 2 Spectral Distribution

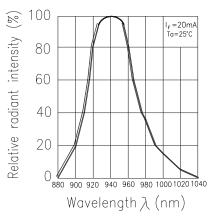


Fig. 4 Forward Current vs. Forward Voltage

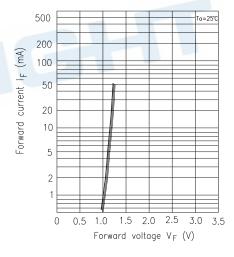
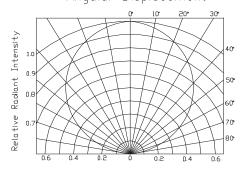


Fig. 6 Relative Radiant Intensity vs.

Angular Displacement



### Typical Electrical/Optical/Characteristics Curves for PT

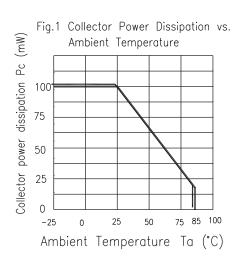


Fig. 3 Relative Collector Current vs. Ambient Temperature

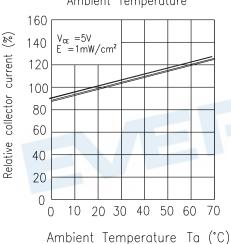


Fig.5 Spectral Sensitivity

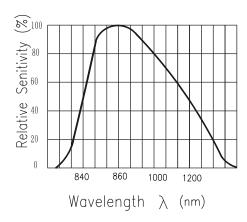


Fig.2 Collector Dark Current vs.

Ambient Temperature

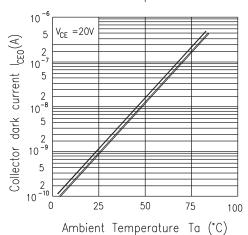


Fig.4 Collector Current vs. Irradiance

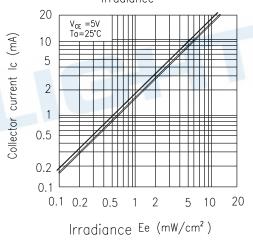
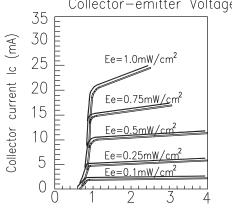


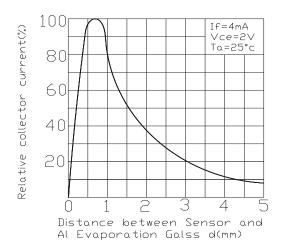
Fig.6 Collector Current vs.
Collector-emitter Voltage



Collector-emitter Voltage V CE (V)

## Typical Electrical/Optical/Characteristics Curves for ITR

Fig.7 Relative Collector Current vs.
Distance between Sensor and
Al Evaporation Galss



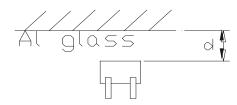
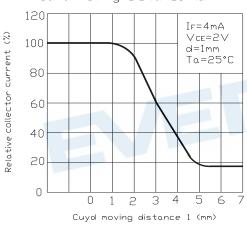


Fig.8 Relative Collector Current vs. Card Moving Distance (1)



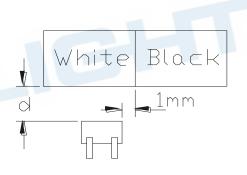
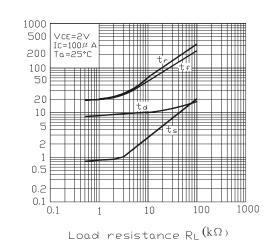
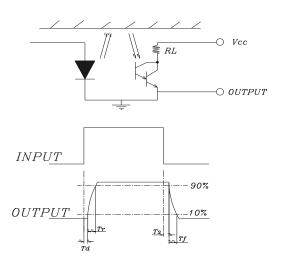


Fig.9 Response Time vs. Load Resistance



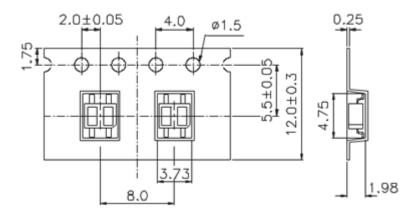


Response time ( $\mu_{\rm S}$ )



### **Taping Dimension**

feeding direction



General Tolerance ±0.1 UNIT:mm

### **Packing Quantity Specification**

- 1. 1000 Pcs/ 1Reel
- 2. 15 Reel / 1 Box
- 3. 2 Box / 1 Carton

### **Recommended Method of Storage**

The following are general recommendations for moisture sensitive level (MSL) 4 storage and use:

- Shelf life in sealed bag: 12 months at < 40 °C and < 90% relative humidity (RH)
- After bag is opened, devices that will be subjected to reflow solder or other high temperature process must:
  - a) Mounted within 72 hours of factory conditions < 30 °C/60% RH, or
  - b) Stored at <20% RH
- Devices require bake, before mounting, if:

Humidity Indicator Card is > 20% when read at  $23 \pm 5$  °C

- If baking is required, devices may be baked:
  - a) 192 hours at 40°C, and <5% RH(dry air/nitrogen) or
  - b) 96 hours at 60°C, and <5% RH for all device containers
  - c) 24 hours at 125 °C

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#### **Disclaimer**

- 1.EVERLIGHT reserves the right(s) on the adjustment of product material mix for the specification.
- 2. The product meets EVERLIGHT published specification for a period of twelve (12) months from date of shipment.
- 3. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 4. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from the use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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